

PHOTOCOUPLER PS2705A-1

HIGH ISOLATION VOLTAGE SOP PHOTOCOUPLER

-NEPOC Series-

DESCRIPTION

The PS2705A-1 is an optically coupled isolator containing a GaAs light emitting diode and an NPN silicon phototransistor to realize an excellent cost performance.

This package is SOP (Small Outline Package) type and has shield effect to cut off ambient light.

It is designed for high density mounting applications.

FEATURES

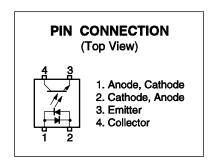
- · AC input response
- High isolation voltage (BV = 3 750 Vr.m.s.)
- · SOP (Small Outline Package) type
- Ordering number of taping product: PS2705A-1-F3, F4: 3 500 pcs/reel
- · Pb-Free product

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- · Safety standards
 - UL approved: No. E72422
 - CSA approved: No. CA 101391 (CA5A, CAN/CSA-C22.2 60065, 60950)
 - DIN EN60747-5-2 (VDE0884 Part2) approved (Option)

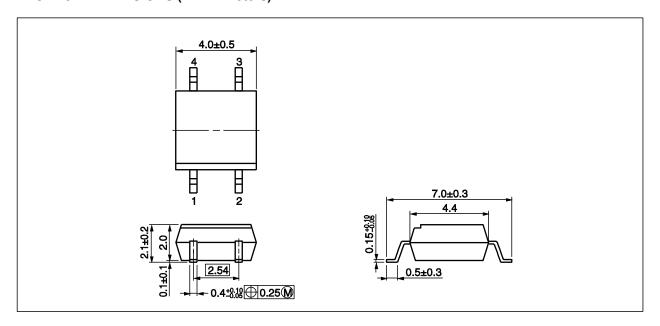
APPLICATIONS

- Hybrid IC
- Telephone/FAX.
- FA/OA equipment
- · Programmable logic controllers
- Power supply



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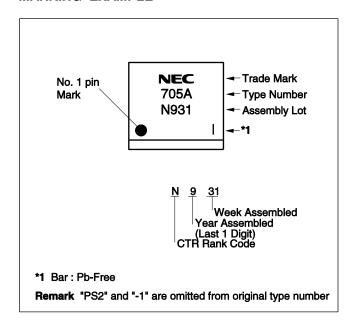
PACKAGE DIMENSIONS (in millimeters)



<R> PHOTOCOUPLER CONSTRUCTION

Parameter	Unit (MIN.)		
Air Distance	5 mm		
Outer Creepage Distance	5 mm		
Inner Creepage Distance	2.5 mm		
Isolation Distance	0.3 mm		

<R> MARKING EXAMPLE



<R> ORDERING INFORMATION

Part Number	Order Number	Solder Plating Specification	Packing Style	Safety Standard Approval	Application *1 Part Number
PS2705A-1	PS2705A-1-A	Pb-Free	Magazine case 100 pcs	Standard products	PS2705A-1
PS2705A-1-F3	PS2705A-1-F3-A		Embossed Tape 3 500 pcs/reel	(UL, CSA approved)	
PS2705A-1-F4	PS2705A-1-F4-A				
PS2705A-1-V	PS2705A-1-V-A		Magazine case 100 pcs	DIN EN60747-5-2	
PS2705A-1-V-F3	PS2705A-1-V-F3-A		Embossed Tape 3 500 pcs/reel	(VDE0884 Part2)	
PS2705A-1-V-F4	PS2705A-1-V-F4-A			Approved (Option)	

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25°C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current (DC)	lF	±30	mA
	Power Dissipation Derating	⊿P₀/°C	0.8	mW/°C
	Power Dissipation	Po	80	mW
	Peak Forward Current*1	IFP	±0.5	Α
Transistor	Collector to Emitter Voltage	Vceo	70	V
	Emitter to Collector Voltage	Veco	5	V
	Collector Current	Ic	30	mA
	Power Dissipation Derating	⊿Pc/°C	1.5	mW/°C
	Power Dissipation	Pc	150	mW
Isolation Voltage*2		BV	3 750	Vr.m.s.
Operating Ambient Temperature		TA	-55 to +100	°C
Storage Temperature		T _{stg}	-55 to +150	°C

^{*1} PW = 100 μ s, Duty Cycle = 1%

^{*2} AC voltage for 1 minute at $T_A = 25$ °C, RH = 60% between input and output. Pins 1-2 shorted together, 3-4 shorted together.

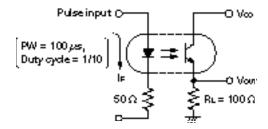
ELECTRICAL CHARACTERISTICS (TA = 25°C)

	Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Diode	Forward Voltage	VF	IF = ±5 mA		1.2	1.4	V
	Terminal Capacitance	Ct	V = 0 V, f = 1.0 MHz		20		pF
Transistor	Collector to Emitter Dark Current	Iceo	I _F = 0 mA, V _{CE} = 70 V			100	nA
Coupled	Current Transfer Ratio (Ic/IF)*1	CTR	$I_F = \pm 5 \text{ mA}, \text{ Vce} = 5 \text{ V}$	50		300	%
	Collector Saturation Voltage	VCE (sat)	$I_F = \pm 10 \text{ mA}, I_C = 2 \text{ mA}$		0.13	0.3	V
	Isolation Resistance	R _{I-O}	Vi-o = 1.0 kVdc	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1.0 MHz		0.4		pF
	Rise Time *2	t r	$Vcc = 5 \text{ V}, \text{ Ic} = 2 \text{ mA}, \text{ RL} = 100 \Omega$		5		μS
	Fall Time *2	t f			7		

*1 CTR rank

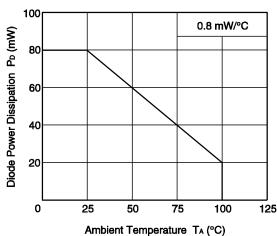
N: 50 to 300 (%) L: 100 to 300 (%) M: 50 to 150 (%)

*2 Test circuit for switching time



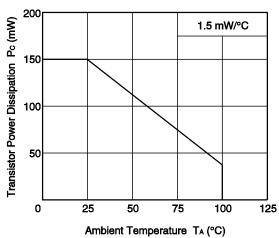
TYPICAL CHARACTERISTICS (TA = 25°C, unless otherwise specified)



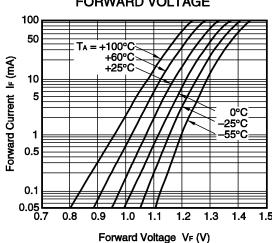


AMBIENT TEMPERATURE

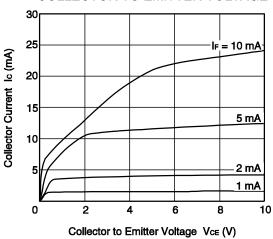
TRANSISTOR POWER DISSIPATION vs.



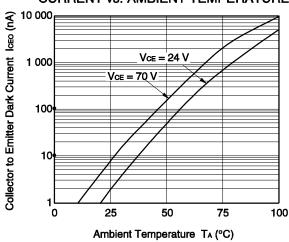
FORWARD CURRENT vs. **FORWARD VOLTAGE**



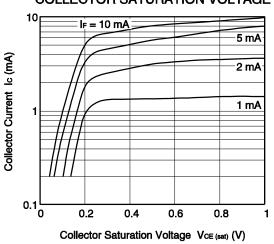
COLLECTOR CURRENT vs. **COLLECTOR TO EMITTER VOLTAGE**



COLLECTOR TO EMITTER DARK CURRENT vs. AMBIENT TEMPERATURE

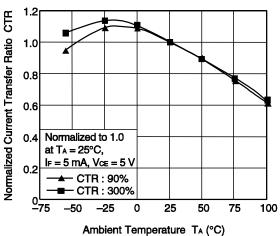


COLLECTOR CURRENT vs. **COLLECTOR SATURATION VOLTAGE**

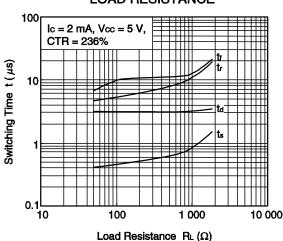


Remark The graphs indicate nominal characteristics.

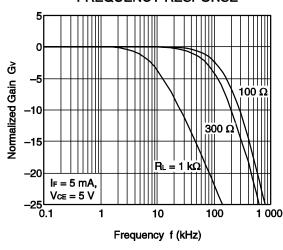
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



SWITCHING TIME vs. LOAD RESISTANCE

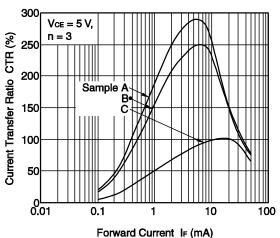


FREQUENCY RESPONSE

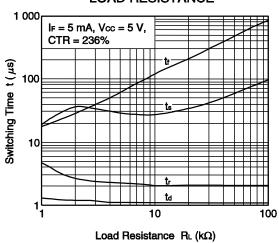


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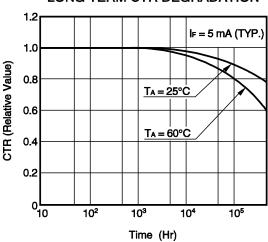
CURRENT TRANSFER RATIO vs. FORWARD CURRENT



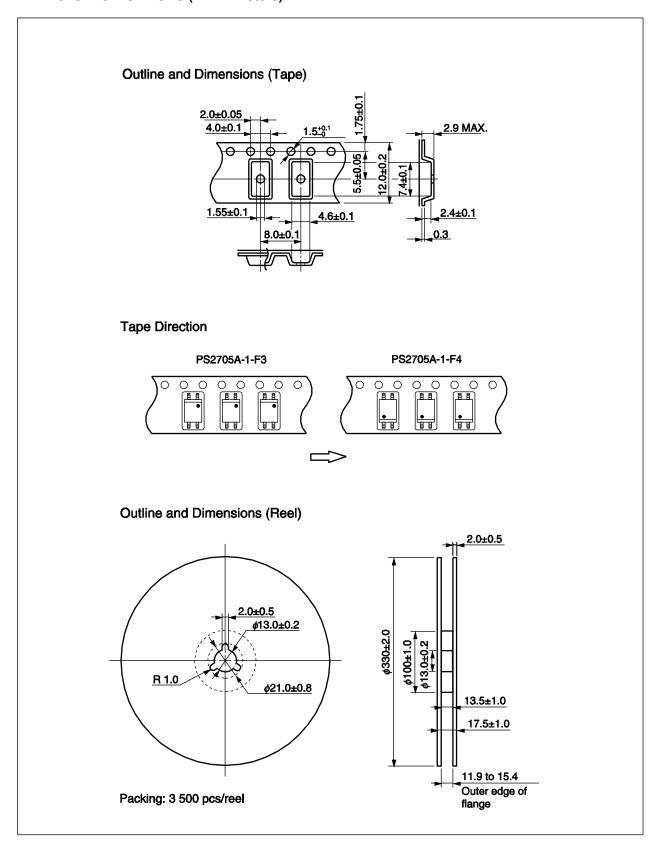
SWITCHING TIME vs. LOAD RESISTANCE



LONG TERM CTR DEGRADATION



TAPING SPECIFICATIONS (in millimeters)



NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

· Peak reflow temperature 260°C or below (package surface temperature)

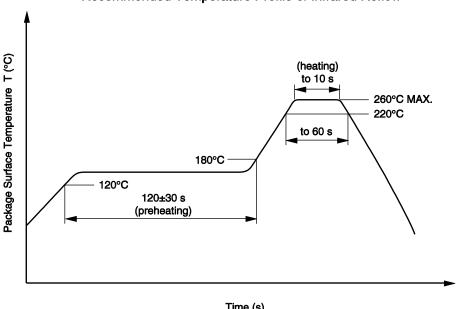
• Time of peak reflow temperature 10 seconds or less • Time of temperature higher than 220°C 60 seconds or less

 Time to preheat temperature from 120 to 180°C 120±30 s · Number of reflows Three

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

 Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

· Preheating conditions 120°C or below (package surface temperature)

· Number of times One (Allowed to be dipped in solder including plastic mold portion.)

Rosin flux containing small amount of chlorine (The flux with a maximum chlorine • Flux

content of 0.2 Wt% is recommended.)

(3) Soldering by Soldering Iron

• Peak Temperature (lead part temperature) 350°C or below · Time (each pins) 3 seconds or less

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

(a) Soldering of leads should be made at the point 1.5 to 2.0 mm from the root of the lead

(b) Please be sure that the temperature of the package would not be heated over 100°C

(4) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output transistor may enter the on state, even if the voltage is within the absolute maximum ratings.

3. Measurement conditions of current transfer ratios (CTR), which differ according to photocoupler

Check the setting values before use, since the forward current conditions at CTR measurement differ according to product.

When using products other than at the specified forward current, the characteristics curves may differ from the standard curves due to CTR value variations or the like. This tendency may sometimes be obvious, especially below I_F = 1 mA.

Therefore, check the characteristics under the actual operating conditions and thoroughly take variations or the like into consideration before use.

USAGE CAUTIONS

- 1. Protect against static electricity when handling.
- 2. Avoid storage at a high temperature and high humidity.

<R> SPECIFICATION OF VDE MARKS LICENSE DOCUMENT

Parameter	Symbol	Spec.	Unit
Climatic test class (IEC 60068-1/DIN EN 60068-1)		55/100/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.5 \times U_{\text{IORM}}, P_{\text{d}} < 5 \text{pC}$	Uiorm Upr	707 1 060	V _{peak} V _{peak}
Test voltage (partial discharge test, procedure b for all devices) $U_{pr} = 1.875 \times U_{IORM}, \ P_d < 5 \ pC$	U _{pr}	1 325	V_{peak}
Highest permissible overvoltage	Utr	6 000	V _{peak}
Degree of pollution (DIN EN 60664-1 VDE0110 Part 1)		2	
Comparative tracking index (IEC 60112/DIN EN 60112 (VDE 0303 Part 11))	CTI	175	
Material group (DIN EN 60664-1 VDE0110 Part 1)		III a	
Storage temperature range	Tstg	-55 to +150	°C
Operating temperature range	TA	-55 to +100	°C
Isolation resistance, minimum value VIO = 500 V dc at TA = 25°C VIO = 500 V dc at TA MAX. at least 100°C	Ris MIN. Ris MIN.	10 ¹² 10 ¹¹	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I _F , Psi = 0) Power (output or total power dissipation) Isolation resistance	Tsi Isi Psi	150 300 500	°C mA mW
V _{IO} = 500 V dc at T _A = Tsi	Ris MIN.	10 ⁹	Ω

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M8E0904E

Caution

GaAs Products

This product uses gallium arsenide (GaAs).

GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.

- Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
- 1. Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
- 2. Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
- Do not burn, destroy, cut, crush, or chemically dissolve the product.
- Do not lick the product or in any way allow it to enter the mouth.